NSN 5962-01-370-8091

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View Online at https://aerobasegroup.com/nsn/5962-01-370-8091

Body Length:

Between 0.342 inches and 0.358 inches

Body Width:

Between 0.342 inches and 0.358 inches

Body Height:

Between 0.060 inches and 0.100 inches

Maximum Power Dissipation Rating:

1.1 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

5895-01-305-8863 recorder, signal data

Features Provided:

Bipolar and programmed and high impedance and w/clock and bidirectional and electrostatic sensitive

Inclosure Material:

Ceramic

Inclosure Configuration:

Leadless flat pack

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

14 input

Case Outline Source And Designator:

C-2 mil-m-38510

Current Rating Per Characteristic:

90.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Product Name:

Registered and-or gate array

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 12.0 volts power source

Time Rating Per Chacteristic:

50.00 nanoseconds propagation delay time, high to low level output and 50.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Pal

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 leadless

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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